

#### **Product Features**

- Greater than +34 dBm IIP3
- 77 dBc 2x1 Spur Rejection in IF Band
- RF 1000 2000 MHz
- LO 1000 2000 MHz
- IF 10 1000 MHz
- +24 dBm LO Drive Level
- +5V Bias (40 mA)
- SMT J-Lead Package

### **Applications**

• CATV Head-End Equipment

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#### **Product Description**

The HMJ7-1 is a high dynamic range GaAs FET mixer. This active broadband mixer realizes a typical third order intercept point of +34 dBm at an LO drive level of +21 dBm. The HMJ7-1 also provides excellent suppression of spurious intermodulation products, greater than 67 dBc, system meeting DOCSIS2 and Euro DOCSIS requirements. The HMJ7-1 is a specially screened version of the HMJ7 mixer meeting all of the performance requirements of the HMJ7 with 21 dBm bo power, but also meeting the suppression requirements for intermodulation products at a 24 dBm LO powerlevel.

The HMJ7-1 comes in a low cost, 22-pin J Lead package. The combination of high dynamic range and spurious suppression makes the HMJ7-1 an ideal choice for CATV headend transmission equipment and other applications requiring a broadband mixer in the 1000 MHz to 2000 MHz frequency range.



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Function	Pin No.
IF	2
🗸 LO	13
RF	21
+5V	10
Ground	All other pins

Specifications V			~ ~ ~	$\sim$	$\sim$
Parameter	Units	Min	Тур	Max	Condition
RF Frequency Range	MHz		1000-2000	r 1	
LO Frequency Range	MHz		1000-/2000		
IF Frequency Range	MHz	$\geq$	10 1000	. (I	
SSB Conversion Loss	dB		8.5	95	9
Noise Figure	dB	20	10.5	$\langle \rangle \rangle$	
LO-RF Isolation	dB		24	$\sim$	
LO-IF Isolation	dB	(24)	30 🗸		
<b>RF-IF</b> Isolation	dB 🗸	$\sim$	.24	$\sim$	
Input IP3	dBm	29	34	U I	RF = 1018 MHz @ 0 dBm
RF Return Loss	dB	$\sum$			
LO Return Loss	, dB		$\mathcal{A}$		
IF Return Loss	dB	$\bigcap$	<b>1</b>		
Spurious Rejection <sup>(2)</sup>	dBc	67	) 77		LO = +24  dBm, IF freq = $150 - 540  MHz$ , $640 - 1000  MHz$
Spurious Rejection <sup>(2)</sup>	dBc	76	77		LO = +24  dBm, IF freq = $540 - 640  MHz$
Input P1dB	dBm	(Th	+23		
LO Drive Level	dBm		+21		
DC Current at +5V Bias	mA 🖌	$\langle \rangle$	40	60	

Test conditions unless where the IM spur = 2 \* C, Rf = 1088.75 MHz @ 0 dBm, LO = 21 dBm, IF = 50, 650, 860 MHz in a high-side LO configuration.
The 2x1 spur is tested where the IM spur = 2 \* RF input = DQ where RF input = 1090 MHz @ -14 dBm, LO = 1190 to 2090 MHz @ 24 dBm, IM spur = output frequency. The IM spur level is specified in dBc with respect to the desired IF frequency calculateds. IF output = LO - RF input.

## Absolute Maximum Rating

Parameters Rating	
Operating Case Temperature -40 to +85 °C	
Storage Temperature -65 to +100 °C	
Maximum Input Power +25 dBm	

### **Ordering Information**

Part No.	Description
HMJ7-1	High Dynamic Range FET Mixer

Operation of this device above any of these parameters may cause permanent damage

Specifications and information are subject to change without notice

TriQuint 🏈 SEMICONDUCTOR









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